

Integrated microfluidic test-bed for energy conversion devices (Supporting Information)

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2. Cross-sectional potential profiles across microfluidic channels

As described in the main text, the dimensions in the chip were selected so that the ohmic drop across channels was negligible. The 2D potential pattern shown below was calculated for a high current density scenario (80 mA/cm^2) and demonstrates that even under those conditions the potential drop across electrodes does not exceed 10 mV.

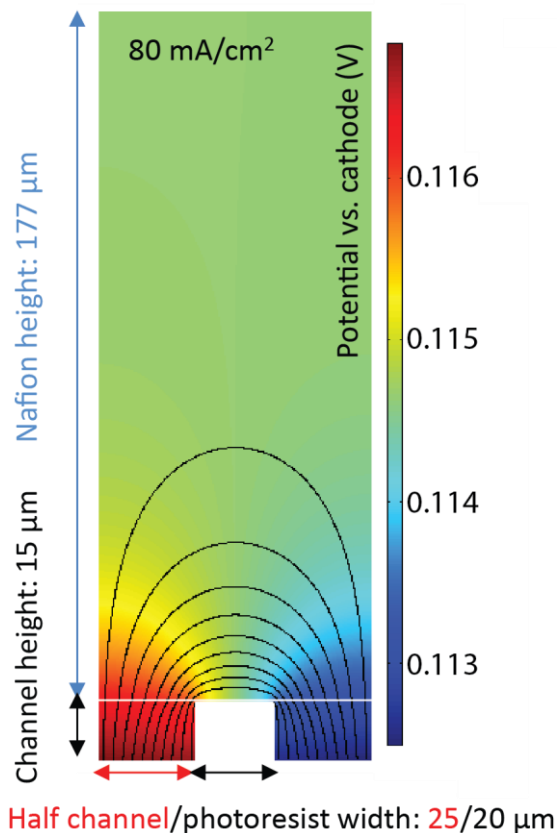


Figure S2. Potential drop pattern across two channels for a current density of 80 mA/cm^2 .